

Product data sheet

1. General description

Planar passivated high commutation three quadrant triac in a TO92 plastic package. This triac is intended for use in motor control circuits where very high blocking voltage can occur. It is used in applications where "high junction operating temperature capability ($T_{i(max)} = 150$ °C)" is required.

2. Features and benefits

- 3Q technology for improved noise immunity
- High junction operating temperature capability (T_{j(max)} = 150 °C)
- Over-voltage withstand capability to IEC 61000-4-5
- · Planar passivated for voltage ruggedness and reliability
- High voltage capability
- High immunity to false tun on by dV/dt
- Triggering in three quadrants only

3. Applications

- AC fan, pump and compressor controls
- · Highly inductive, resistive and safety loads
- · Large and small appliances (White Goods)
- · Reversing induction motor controls e.g. vertical axis washing machines

4. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{DRM}	repetitive peak off-state voltage		-	-	1000	V
I _{T(RMS)}	RMS on-state current	full sine wave; T _{lead} ≤ 57 °C; <u>Fig.1; Fig. 2</u> ; <u>Fig. 3</u>	-	-	2	A
I _{TSM}	non-repetitive peak on- state current	full sine wave; $T_{j(init)}$ = 25 °C; t_p = 20 ms; Fig. 4; Fig. 5	-	-	25	A
		full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms	-	-	27.5	А
Tj	junction temperature		-	-	150	°C
Static ch	aracteristics	·				
I _{GT}	gate trigger current	$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G+};$ $\text{T}_{j} = 25 \text{ °C}; \text{ Fig. 7}$	-	-	35	mA
		V _D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u>	-	-	35	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2- G-};$ T _i = 25 °C; <u>Fig. 7</u>	-	-	35	mA

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I _H	holding current	g current $V_{D} = 12 \text{ V}; \text{ T}_{j} = 25 \text{ °C}; \text{ Fig. 9}$		-	-	40	mA
V _T	on-state voltage	I _T = 3 A; T _j = 25 °C; <u>Fig. 10</u>		-	-	1.5	V
Dynamic	characteristics						
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 670 V; T _j = 150 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit		1000	-	-	V/µs

5. Pinning information

Table 2. P	Table 2. Pinning information									
Pin	Symbol	Description	Simplified outline	Graphic symbol						
1	T2	main terminal 2	 1	Ν						
2	G	gate								
3	Τ1	main terminal 1	3 2 1 TO-92 (SOT54)	sym051						

6. Ordering information

Table 3. Ordering information									
Type number	Package Name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date			
BTA202-1000CT	TO92	BTA202-1000CTEP	Bulk	1000	SOT54	14-Nov-2013			
BTA202-1000CT	TO92	BTA202-1000CTQP	Tape & Reel	2000	SOT54 wide pitch	14-Nov-2013			

7. Marking

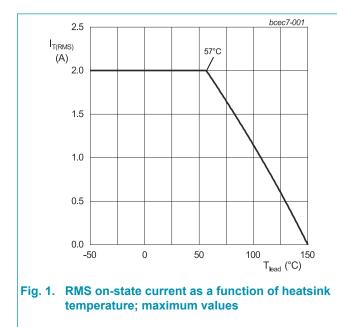
Table 4. Marking codes						
Type number	Marking codes					
BTA202-1000CT	2-10CT					

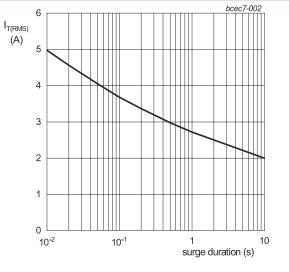
8. Limiting values

Table 5. Limiting values

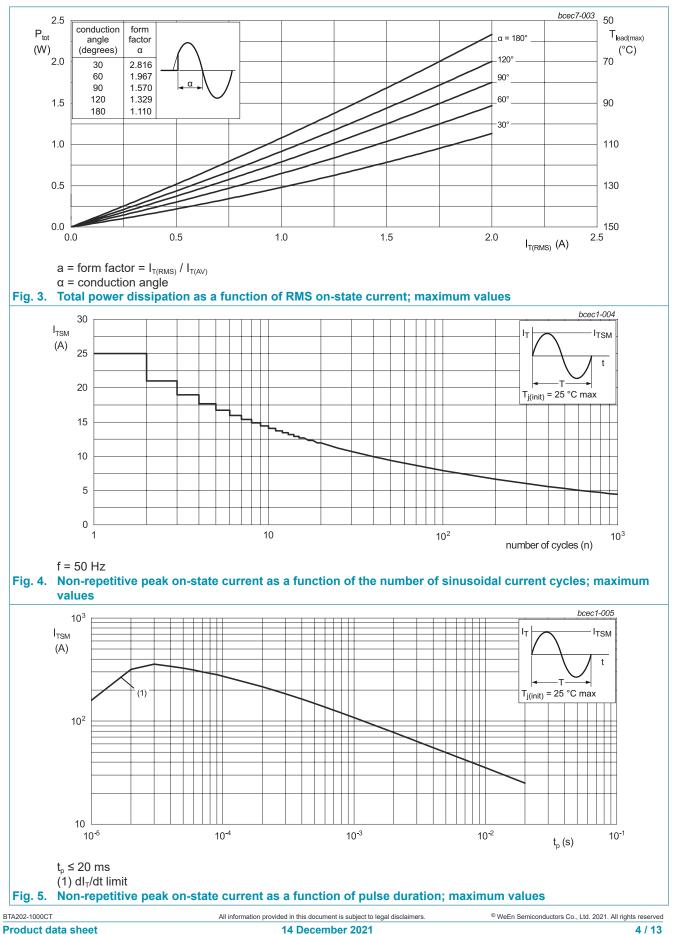
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{drm}	repetitive peak off-state voltage		-	1000	V
I _{T(RMS)}	RMS on-state current	full sine wave; T _{lead} ≤ 57 °C; <u>Fig.1; Fig. 2</u> ; <u>Fig. 3</u>	-	2	A
I _{TSM}	non-repetitive peak on- state current	full sine wave; $T_{j(init)}$ = 25 °C; t_p = 20 ms; Fig. 4; Fig. 5	-	25	A
		full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms	-	27.5	А
l ² t	I ² t for fusing	t _p = 10 ms; sine wave pulse	-	3.125	A ² s
dl _⊤ /dt	rate of rise of on-state current	I _G = 70 mA	-	100	A/µs
I _{GM}	peak gate current		-	2	А
P _{GM}	peak gate power		-	5	W
P _{G(AV)}	average gate power	over any 20 ms period	-	0.5	W
T _{stg}	storage temperature		-40	150	°C
T _i	junction temperature		-	150	°C



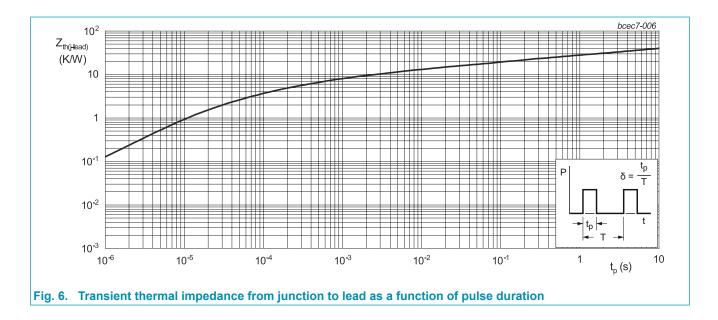






9. Thermal characteristics

Table 6. Theri	mal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{\text{th(j-lead)}}$	thermal resistance from junction to lead	<u>Fig. 6</u>	-	-	40	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient	in free air	-	150	-	K/W



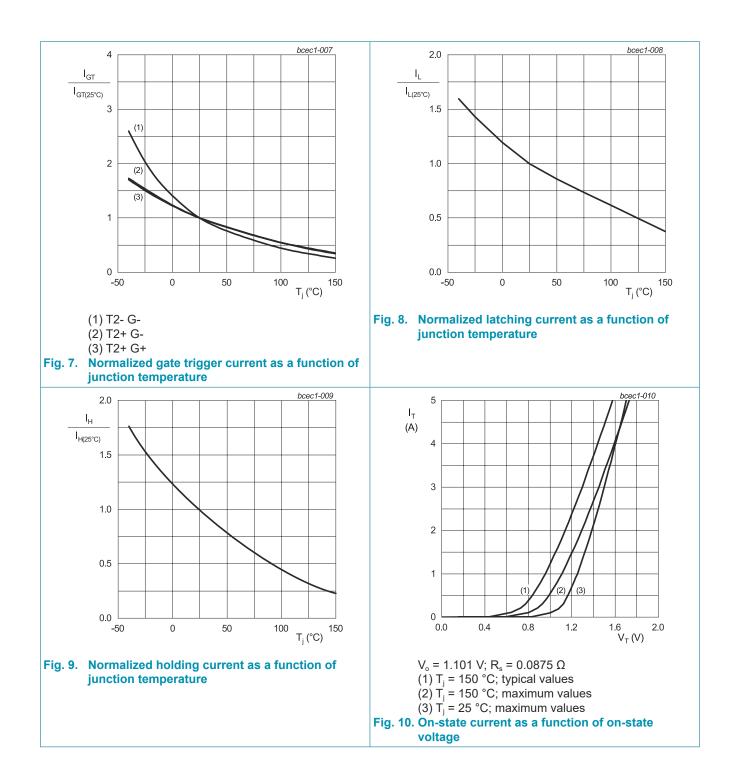
10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
	racteristics					
I _{GT}	gate trigger current	$V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ T2+ G+};$ $T_j = 25 \text{ °C}; \text{ Fig. 7}$	-	-	35	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G-};$ T _j = 25 °C; Fig. 7	-	-	35	mA
		V_{D} = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 7</u>	-	-	35	mA
IL	latching current	$V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2+ G+};$ $\text{T}_j = 25 ^\circ\text{C}; \text{ Fig. 8}$	-	-	60	mA
		V_{D} = 12 V; I _G = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 8</u>	-	-	70	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{G} = 0.1 \text{ A}; \text{ T2- G-};$ T _j = 25 °C; Fig. 8	-	-	60	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	-	40	mA
V _T	on-state voltage	ate voltage $I_{T} = 3 \text{ A}; T_{j} = 25 \text{ °C}; Fig. 10$		-	1.5	V
$V_{\rm GT}$	gate trigger voltage	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C Fig. 11	-	0.8	1	V
		V _D = 400 V; I _T = 0.1 A; T _j = 150 °C	0.2	0.45	-	V
I _D	off-state current	V _D = 1000 V; T _j = 25 °C	-	-	10	μA
		V _D = 1000 V; T _j = 150 °C	-	-	1	mA
I _R	reverse current	V _R = 1000 V; T _j = 25 °C	-	-	10	μA
		V _R = 1000 V; T _j = 150 °C	-	-	1	mA
Dynamic	characteristics					_
dV _D /dt	rate of rise of off-state voltage	$V_{DM} = 670 \text{ V}; \text{ T}_{j} = 150 \text{ °C}; (V_{DM} = 67\% \text{ of } V_{DRM});$ exponential waveform; gate open circuit	1000	-	-	V/µs
dI _{com} /dt	rate of change of commutating current	$V_D = 400 \text{ V}; \text{ T}_j = 150 \text{ °C}; \text{ I}_{T(RMS)} = 2 \text{ A}; $ $dV_{com}/dt = 20 \text{ V}/\mu \text{s}; \text{ gate open circuit}; $ snubberless condition	6	-	-	A/ms
		$V_D = 400 \text{ V}; \text{ T}_j = 150 \text{ °C}; \text{ I}_{T(RMS)} = 2 \text{ A};$ $dV_{com}/dt = 10 \text{ V}/\mu\text{s}; \text{ gate open circuit}$	8	-	-	A/ms
		V_{D} = 400 V; T_{j} = 150 °C; $I_{T(RMS)}$ = 2 A; dV _{com} /dt = 1 V/µs; gate open circuit	10	-	-	A/ms

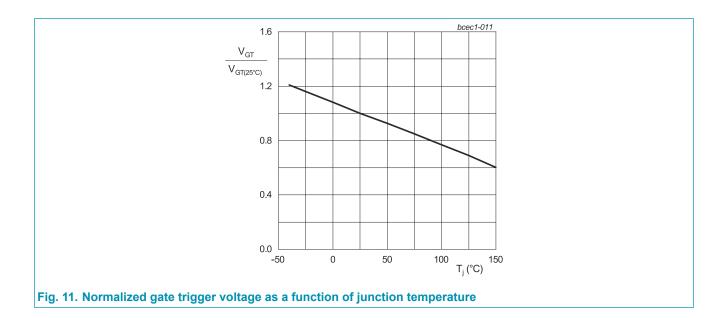
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3Q Hi-Com Triac

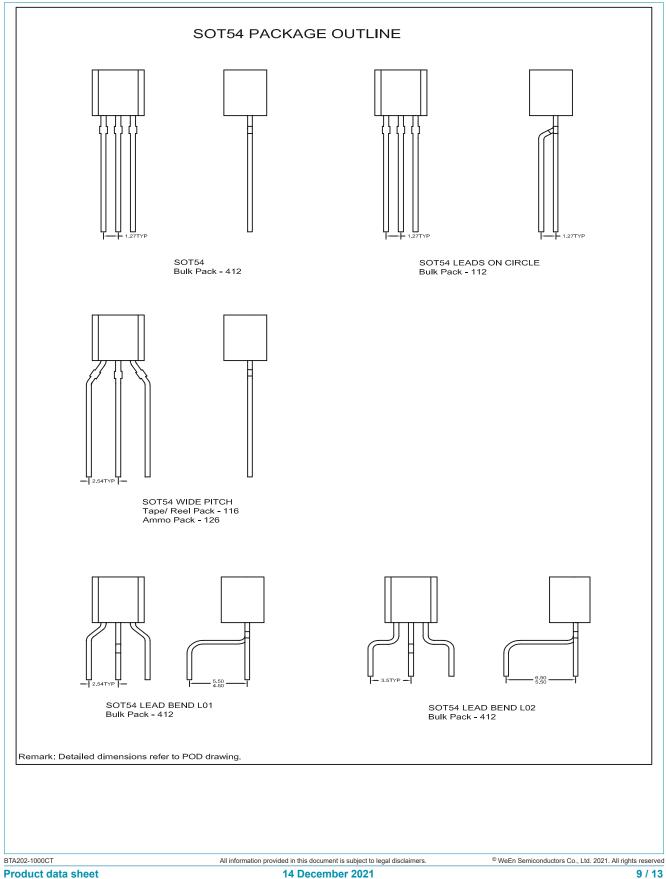
BTA202-1000CT

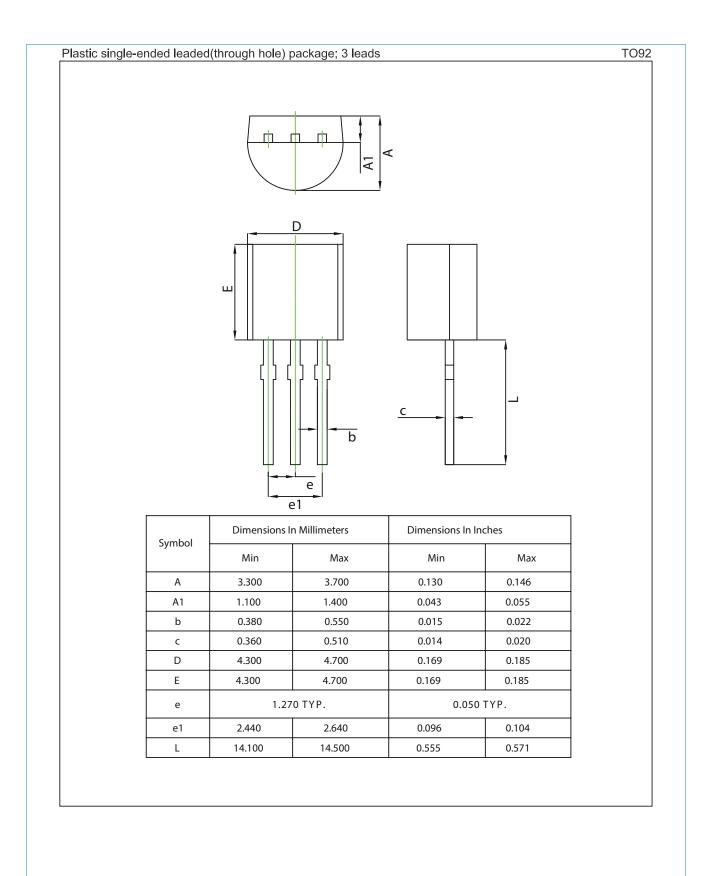


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11. Package outline





12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

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